

MMBTA43LT1 Datasheet



MMBTA43LT1-DG
onsemi
MMBTA43LT1
TRANS NPN 200V 0.05A SOT23-3
Bipolar (BJT) Transistor NPN 200 V 50 mA 50MHz 22 5 mW Surface Mount SOT-23-3 (TO-236)

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MMBTA43LT1	onsemi
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN	50 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
200 V	500mV @ 2mA, 20mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
100nA (ICBO)	40 @ 30mA, 10V
Power - Max:	Frequency - Transition:
225 mW	50MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	SOT-23-3 (TO-236)
Base Product Number:	
MMBTA43	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
RoHS non-compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	

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High Voltage Transistors NPN Silicon MMBTA42L, SMMBTA42L, MMBTA43L

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Characteristic	Symbol	Value	Unit
Collector – Emitter Voltage MMBTA42, SMMBTA42 MMBTA43	V _{CEO}	300 200	Vdc
Collector – Base Voltage MMBTA42, SMMBTA42 MMBTA43	V _{CBO}	300 200	Vdc
Emitter – Base Voltage MMBTA42, SMMBTA42 MMBTA43	V _{EBO}	6.0 6.0	Vdc
Collector Current – Continuous	Ι _C	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{sta}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

COLLECTOR BASE



SOT-23 (TO-236) CASE 318 STYLE 6

MARKING DIAGRAMS



*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MMBTA42L, SMMBTA42L, MMBTA43L

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 3) ($I_C = 1.0 \text{ mAdc}, I_B = 0$)	MMBTA42, SMMBTA42 MMBTA43	V _{(BR)CEO}	300 200		Vdc
Collector – Base Breakdown Voltage (I _C = 100 μAdc, I _E = 0)	MMBTA42, SMMBTA42 MMBTA43	V _{(BR)CBO}	300 200		Vdc
Emitter – Base Breakdown Voltage $(I_E = 100 \ \mu Adc, I_C = 0)$		V _{(BR)EBO}	6.0	_	Vdc
	MMBTA42, SMMBTA42 MMBTA43	I _{CBO}		0.1 0.1	μAdc
$ \begin{array}{l} \mbox{Emitter Cutoff Current} \\ (V_{EB} = 6.0 \mbox{ Vdc}, I_{C} = 0) \\ (V_{EB} = 4.0 \mbox{ Vdc}, I_{C} = 0) \end{array} $	MMBTA42, SMMBTA42 MMBTA43	I _{EBO}		0.1 0.1	μAdc
ON CHARACTERISTICS (Note 3)					
DC Current Gain ($I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$) ($I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$)	Both Types Both Types	h _{FE}	25 40		_
$(I_C = 30 \text{ mAdc}, V_{CE} = 10 \text{ Vdc})$	MMBTA42, SMMBTA42 MMBTA43		40 40		
Collector – Emitter Saturation Voltage (I_C = 20 mAdc, I_B = 2.0 mAdc)	MMBTA42, SMMBTA42 MMBTA43	V _{CE(sat)}		0.5 0.5	Vdc
Base-Emitter Saturation Voltage $(I_C = 20 \text{ mAdc}, I_B = 2.0 \text{ mAdc})$		V _{BE(sat)}	-	0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS					
$\label{eq:current-Gain-Bandwidth Product} \begin{aligned} & \text{Current-Gain-Bandwidth Product} \\ & (\text{I}_{C}=10 \text{ mAdc}, \text{V}_{CE}=20 \text{ Vdc}, \text{f}=100 \text{ MHz}) \end{aligned}$		f _T	50	_	MHz
Collector-Base Capacitance (V_{CB} = 20 Vdc, I_E = 0, f = 1.0 MHz)	MMBTA42, SMMBTA42 MMBTA43	C _{cb}		3.0 4.0	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

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MMBTA42L, SMMBTA42L, MMBTA43L

TYPICAL CHARACTERISTICS



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MMBTA42L, SMMBTA42L, MMBTA43L

TYPICAL CHARACTERISTICS



ORDERING INFORMATION

Device Order Number	Package Type	Shipping [†]
MMBTA42LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
SMMBTA42LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBTA42LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel
SMMBTA42LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel
MMBTA43LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**



MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

DATE 14 AUG 2024

SCALE 4:1













XXX = Specific Device Code Μ = Date Code

= Pb-Free Package .

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS				
DIM	MIN	NOM	МАХ	
А	0.89	1.00	1.11	
A1	0.01	0.06	0.10	
b	0.37	0.44	0.50	
С	0.08	0.14	0.20	
D	2.80	2.90	3.04	
E	1.20	1.30	1.40	
е	1.78	1.90	2.04	
L	0.30	0.43	0.55	
L1	0.35	0.54	0.69	
ΗE	2.10	2.40	2.64	
Т	0°		10°	

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2.

CONTROLLING DIMENSIONS: MILLIMETERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PPOTPUSIONS OR GATE BURRS. 3.

4. PROTRUSIONS, OR GATE BURRS.

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE		
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27:	STYLE 28:				

PIN 1. CATHODE PIN 1. ANODE 2. CATHODE 2. ANODE 3. CATHODE 3. ANODE

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Image: Second	Herein and the state of the	Handbard Barran and Angel	





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